MA22D41

Silicon epitaxial planar type

For rectification

Overview

MA22D41 is optimal for general circuit supplies.

■ Features

- \bullet Forward current (Average) $I_{F(AV)} = 2.0$ A rectification is possible
- Low forward voltage V_F

■ Absolute Maximum Ratings $T_a = 25$ °C

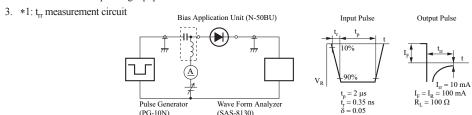
Parameter	Symbol	Rating	Unit	
Reverse voltage	V_R	30	V	
Maximum peak reverse voltage	V _{RM}	30	V	
Forward current (Average) *1	I _{F(AV)}	2.0	A	
Non-repetitive peak forward surge current *2	I _{FSM}	30	A	
Junction temperature	T_j	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	

Note) *1: Lead temperature: T1 = 80°C, DC wave on

■ Electrical Characteristics T_a = 25°C±3°C

Symbol	Conditions	Min	Тур	Max	Unit
V_{F1}	$I_F = 1.0 A$	11/0	.(C)	0.40	V
V_{F2}	$I_{\rm F} = 2.0 {\rm A}$	30, 3		0.45	
I_R	$V_R = 30 \text{ V}$	100		500	μΑ
Ct	$V_R = 10 \text{ V}, f = 1 \text{ MHz}$	1.90	60		pF
t _{rr}	$I_F = I_R = 100 \text{ mA}, I_{rr} = 10 \text{ mA},$ $R_L = 100 \Omega$		19		ns
R _{th(j-a)}	Mounted on an alumina PC board		160		°C/W
R _{th(j-l)}	112, 112		50		°C/W
	V_{F1} V_{F2} I_{R} C_{t} t_{rr} $R_{th(j-a)}$	$\begin{array}{cccc} V_{F1} & I_F = 1.0 A \\ & V_{F2} & I_F = 2.0 A \\ & I_R & V_R = 30 V \\ & C_t & V_R = 10 V, f = 1 MHz \\ & t_{rr} & I_F = I_R = 100 mA, I_{rr} = 10 mA, \\ & R_L = 100 \Omega \\ & R_{th(j-a)} & Mounted on an alumina PC board \\ \end{array}$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.



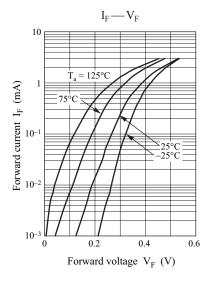
*2: Mounted on an alumina PC board (Board: $20~\text{mm} \times 50~\text{mm}$, Soldering land: $2.0~\text{mm} \times 2.0~\text{mm} + 0.8~\text{mm} \times 2.0~\text{mm}$)

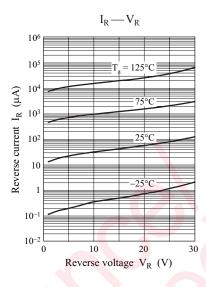
■ Package

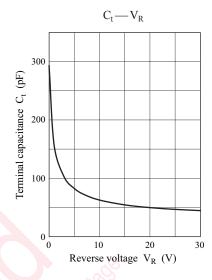
- Code
 - Mini2-F1
- Pin Name
 - 1: Anode
 - 2: Cathode
- Marking Symbol: 3V

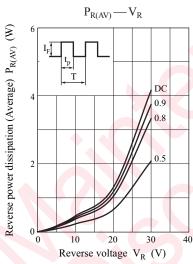
^{*2: 50} Hz sine wave 1 cycle (Non-repetitive peak current)

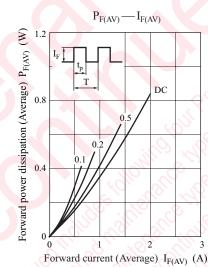
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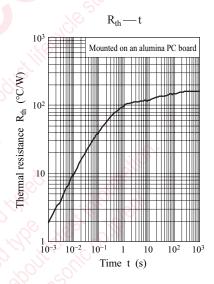


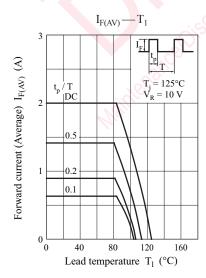








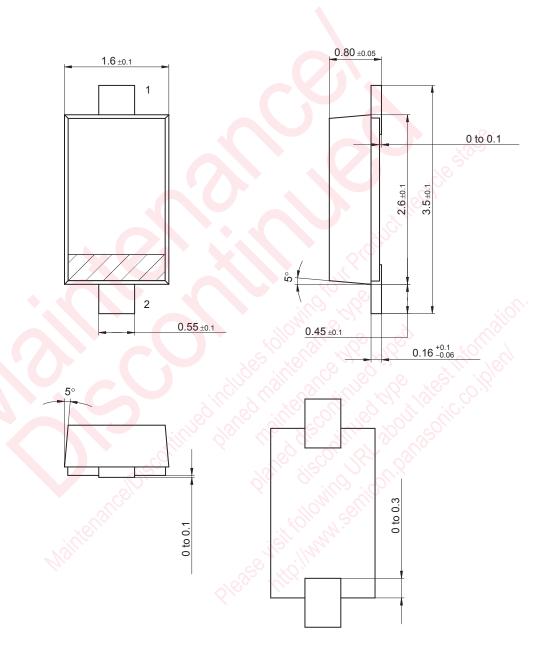




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Panasonic MA22D41

Mini2-F1 Unit: mm



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